

Vishay Siliconix

Automotive P-Channel 30 V (D-S) MOSFET

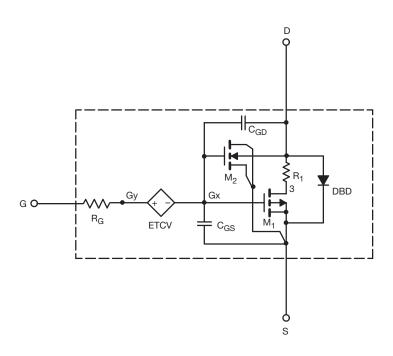
DESCRIPTION

The attached SPICE model describes the typical electrical characteristics of the p-channel vertical DMOS. The subcircuit model is extracted and optimized over the - $55\,^{\circ}\text{C}$ to + $125\,^{\circ}\text{C}$ temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage. A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched C_{gd} model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

SUBCIRCUIT MODEL SCHEMATIC

CHARACTERISTICS

- P-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the 55 °C to + 125 °C Temperature Range
- Model the Gate Charge, Transient, and Diode Reverse Recovery Characteristics



Note

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.

SPICE Device Model SQ3457EV

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SPECIFICATIONS T _J = 25 °C, unless otherwise noted					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	1.7	-	V
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 10 V, I _D = - 6 A	0.038	0.053	Ω
		$V_{GS} = -4.5 \text{ V}, I_D = -4.9 \text{ A}$	0.076	0.083	
Forward Transconductance ^a	9 _{fs}	$V_{DS} = -15 \text{ V}, I_{D} = -5 \text{ A}$	8	9	S
Diode Forward Voltage	V _{SD}	I _S = - 1.6 A	- 0.78	- 0.80	V
Dynamic ^b					
Input Capacitance	C _{iss}	V _{DS} = - 15 V, V _{GS} = 0 V, f = 1 MHz	567	565	pF
Output Capacitance	C _{oss}		149	140	
Reverse Transfer Capacitance	C _{rss}		98	98	
Total Gate Charge	Qg		12	14	
Gate-Source Charge	Q _{gs}	V _{DS} = - 15 V, V _{GS} = - 10 V, I _D = - 5 A	2.1	2.1	nC
Gate-Drain Charge	Q_{gd}		3	3	

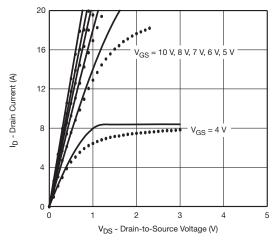
Notes

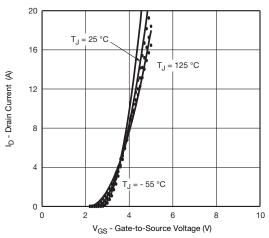
- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

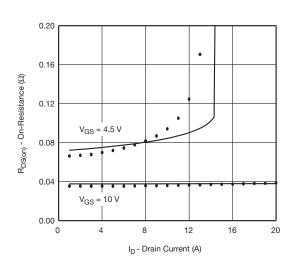


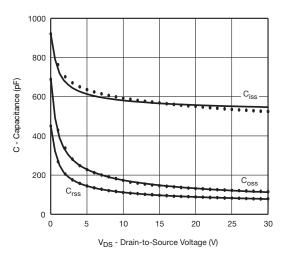
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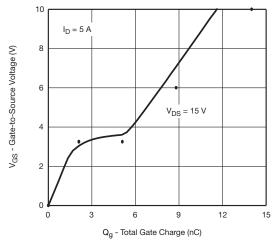
COMPARISON OF MODEL WITH MEASURED DATA $T_J = 25~{}^{\circ}\text{C}$, unless otherwise noted

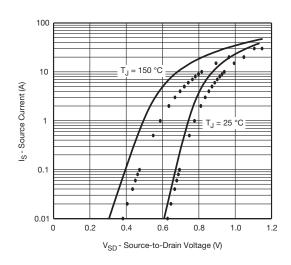












NoteDots and squares represent measured data.



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